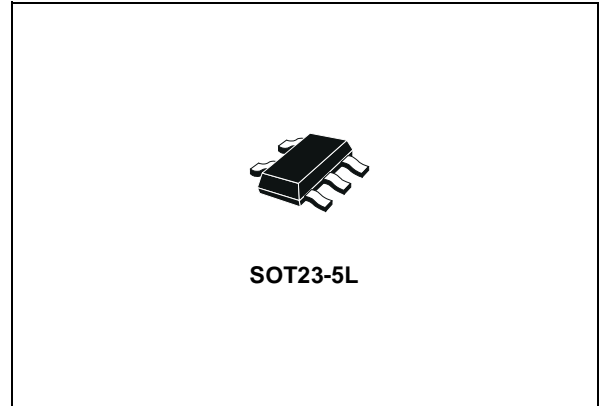


LOW NOISE LOW DROPT VOLTAGE REGULATOR WITH SHUTDOWN FUNCTION

- OUTPUT CURRENT UP TO 200mA
- LOW DROPOUT VOLTAGE (500mV MAX AT $I_{OUT}=200mA$)
- VERY LOW QUIESCENT CURRENT: 0.1 μA IN OFF MODE AND MAX 250 μA IN ON MODE AT $I_{OUT}=0mA$
- LOW OUTPUT NOISE: TYP 30 μV AT $I_{OUT}=60mA$ AND $10Hz < f < 80KHz$
- WIDE RANGE OF OUTPUT VOLTAGES
- INTERNAL CURRENT AND THERMAL LIMIT
- V_{OUT} TOLERANCE $\pm 2\%$ (AT 25°C)

DESCRIPTION

The LK112S is a low dropout linear regulator with a built in electronic switch. The internal switch can be controlled by TTL or CMOS logic levels. The device is ON state when the control pin is pulled to a logic high level. An external capacitor can be used connected to the noise bypass pin to lower the output noise level to 30 μV_{rms} . An internal PNP pass transistor is used to achieve a low dropout voltage.



The LK112S has a very low quiescent current in ON MODE while in OFF MODE the I_q is reduced down to 100nA max. The internal thermal shutdown circuitry limits the junction temperature to below 150°C. The load current is internally monitored and the device will shutdown in the presence of a short circuit or overcurrent condition at the output.

Figure 1: Schematic Diagram

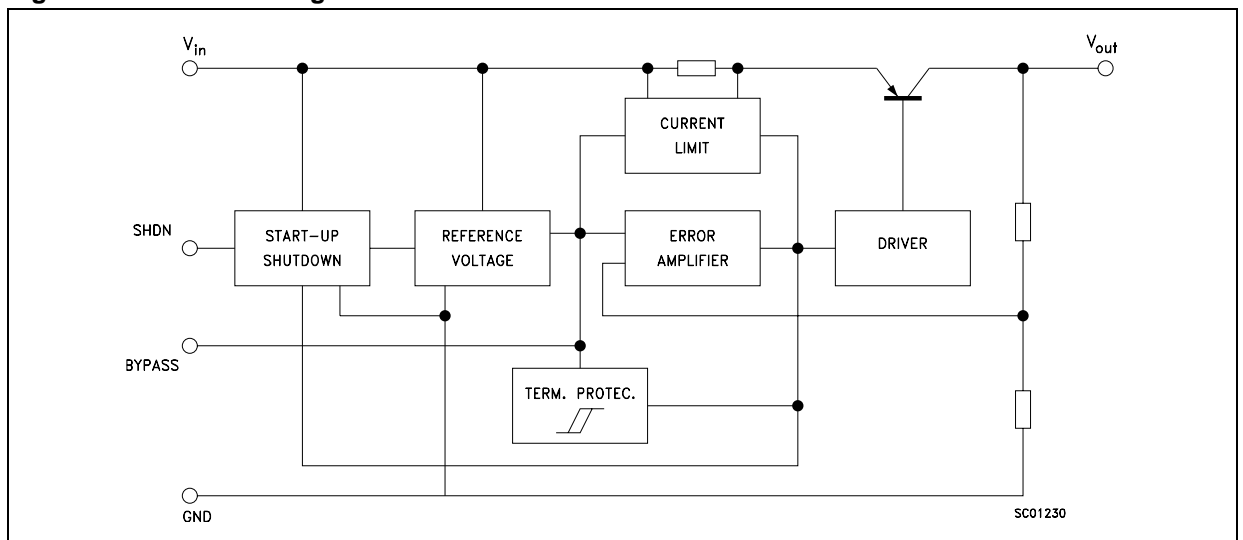


Table 1: Order Codes

Part Number	Output Voltage	V _{OUT} Min	V _{OUT} Max	Test Voltage
LK112SM13TR	1.3V	1.24V	1.36V	2.4V
LK112SM14TR (*)	1.4V	1.34V	1.46V	2.4V
LK112SM15TR	1.5V	1.44V	1.56V	2.4V
LK112SM16TR	1.6V	1.54V	1.66V	2.4V
LK112SM17TR (*)	1.7V	1.64V	1.76V	2.4V
LK112SM18TR	1.8V	1.74V	1.86V	2.4V
LK112SM19TR (*)	1.9V	1.84V	1.96V	2.4V
LK112SM20TR (*)	2.0V	1.94V	2.06V	3.0V
LK112SM21TR	2.1V	2.04V	2.16V	3.1V
LK112SM22TR (*)	2.2V	2.14V	2.26V	3.2V
LK112SM23TR (*)	2.3V	2.24V	2.36V	3.3V
LK112SM24TR (*)	2.4V	2.34V	2.46V	3.4V
LK112SM25TR	2.5V	2.44V	2.56V	3.5V
LK112SM26TR (*)	2.6V	2.54V	2.66V	3.6V
LK112SM27TR (*)	2.7V	2.64V	2.76V	3.7V
LK112SM28TR	2.8V	2.74V	2.86V	3.8V
LK112SM29TR (*)	2.9V	2.84V	2.96V	3.9V
LK112SM30TR	3.0V	2.94V	3.06V	4.0V
LK112SM31TR (*)	3.1V	3.04V	3.16V	4.1V
LK112SM32TR	3.2V	3.14V	3.26V	4.2V
LK112SM33TR	3.3V	3.24V	3.36V	4.3V
LK112SM34TR (*)	3.4V	3.335V	3.465V	4.4V
LK112SM35TR (*)	3.5V	3.435V	3.565V	4.5V
LK112SM36TR	3.6V	3.535V	3.655V	4.6V
LK112SM37TR (*)	3.7V	3.630V	3.770V	4.7V
LK112SM38TR	3.8V	3.725V	3.875V	4.8V
LK112SM39TR (*)	3.9V	3.825V	3.975V	4.9V
LK112SM40TR	4.0V	3.920V	4.080V	5.0V
LK112SM41TR (*)	4.1V	4.020V	4.180V	5.1V
LK112SM42TR (*)	4.2V	4.120V	4.280V	5.2V
LK112SM43TR (*)	4.3V	4.215V	4.385V	5.3V
LK112SM44TR (*)	4.4V	4.315V	4.485V	5.4V
LK112SM45TR (*)	4.5V	4.410V	4.590V	5.5V
LK112SM46TR (*)	4.6V	4.510V	4.690V	5.6V
LK112SM47TR	4.7V	4.605V	4.795V	5.7V
LK112SM48TR (*)	4.8V	4.705V	4.895V	5.8V
LK112SM49TR (*)	4.9V	4.800V	5.000V	5.9V
LK112SM50TR	5.0V	4.900V	5.100V	6.0V
LK112SM55TR	5.5V	5.390V	5.610V	6.5V
LK112M60TR	6.0V	5.880V	6.120V	7.0V
LK112SM80TR	8.0V	7.840V	8.160V	9.0V

(*) Available on request

Table 2: Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V_I	DC Input Voltage	16	V
V_{SHDN}	Shutdown Input Voltage	16	V
I_O	Output Current	Internally limited	
T_{stg}	Storage Temperature Range	-55 to +150	°C
T_{op}	Operating Junction Temperature Range	-30 to +80	°C

Figure 2: Pin Connection (top view)

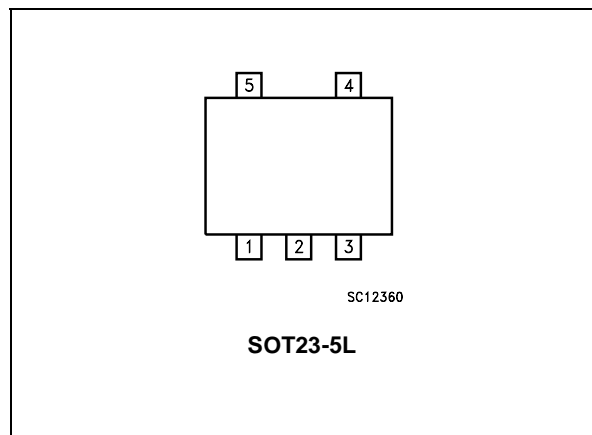


Table 3: Pin Description

Pin N°	Symbol	Name and Function
1	SHDN	Shutdown Input: Disables the regulator when is connected to GND or to positive voltage less than 0.6V
2	GND	Ground Pin: Internally connected to the die attach flag to decrease the total thermal resistance and increase the package ability to dissipate power.
3	Bypass	Bypass Pin: Bypass with 0.1µF to improve the V_{REF} thermal noise performances.
4	OUT	Output Port
5	IN	Input Port

Table 4: Electrical Characteristics For LK112S ($T_j = 25^\circ\text{C}$, $V_{IN}=V_{OUT}+1\text{V}$ (see Note 1), $I_{OUT}=0\text{mA}$, $V_{SHDN}=1.8\text{V}$, $C_I = 1 \mu\text{F}$, $C_O = 2.2\mu\text{F}$, $C_{BYPASS} = 0.1\mu\text{F}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_d	Quiescent Current	ON MODE (except I_{SHDN})		175	250	µA
		OFF MODE $V_I = 8\text{V}$ $V_{SHDN} = 0\text{V}$		0	0.1	µA
V_O	Output Voltage	$I_O = 30\text{mA}$	(see table)			
ΔV_O	Line Regulation	$V_I = V_O+1\text{V}$ to $V_O+6\text{V}$, $V_O \leq 5.6\text{V}$		0.7	20	mV
		$V_I = V_O+1\text{V}$ to $V_O+6\text{V}$, $V_O > 5.6\text{V}$		0.8	40	mV
ΔV_O	Load Regulation	$I_O = 1$ to 60mA		15	30	mV
		$I_O = 1$ to 200mA		30	90	mV
V_d	Dropout Voltage	$I_O = 60 \text{ mA}$ (see Note 2)		0.17	0.24	V
		$I_O = 200 \text{ mA}$ (see Note 2)		0.35	0.5	V
I_{SC}	Short Circuit Current		200			mA
SVR	Supply Voltage Rejection	$V_I = V_O+1.5\text{V}$ $C_{BYP} = 0.1\mu\text{F}$ $C_O = 10\mu\text{F}$ $f = 400\text{Hz}$ $I_O = 30\text{mA}$		55		dB
eN	Output Noise Voltage	B= 10Hz to 80KHz $C_{BYP} = 0.1\mu\text{F}$ $C_O = 10\mu\text{F}$ $V_I = V_O+1.5\text{V}$, $I_O = 60\text{mA}$		30		µVrms
I_{SHDN}	Shutdown Input Current	$V_{SHDN} = 1.8\text{V}$ Output ON		12	35	µA
V_{SHDN}	Shutdown Input Logic	Output ON Output OFF	1.8		0.6	V V
$\Delta V_O/T_j$	Output Voltage Temperature Coefficient	$I_O = 10\text{mA}$		0.09		mV/°C

Note 1: for version with output voltage less than 2V $V_{IN}=2.4\text{V}$
 Note 2: only for version with output voltage more than 2.1V

TYPICAL CHARACTERISTICS (unless otherwise specified $T_j = 25^\circ\text{C}$, $C_I = 1\mu\text{F}$, $C_O = 2.2\mu\text{F}$, $C_{BYP} = 100\text{nF}$)

Figure 3: Output Voltage vs Temperature

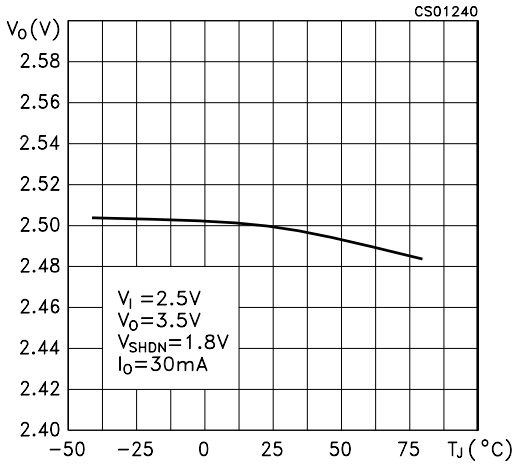


Figure 4: Output Voltage vs Temperature

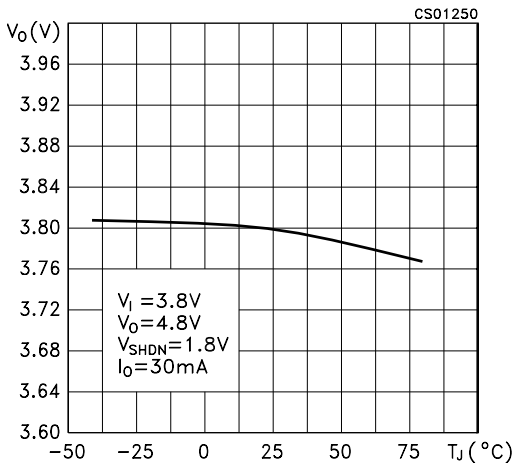


Figure 5: Line Regulation vs Temperature

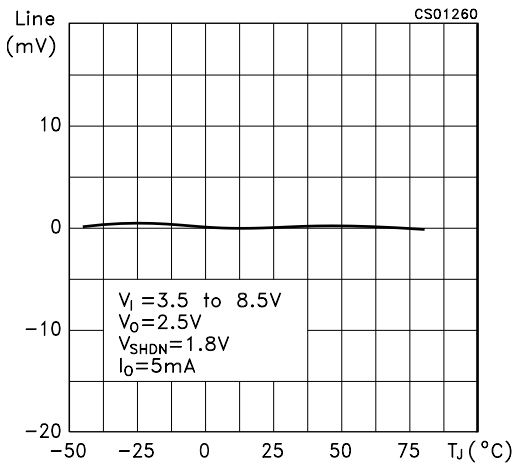


Figure 6: Load Regulation vs Temperature

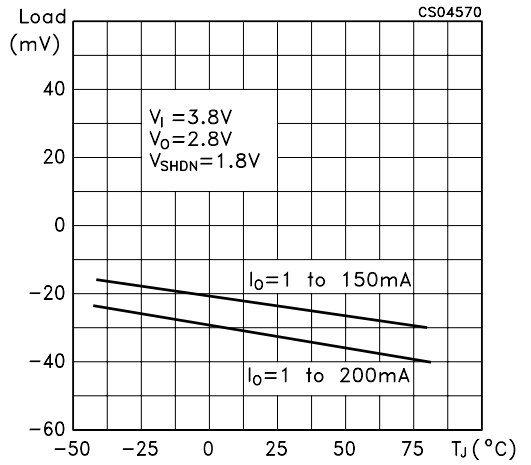


Figure 7: Dropout Voltage vs Temperature

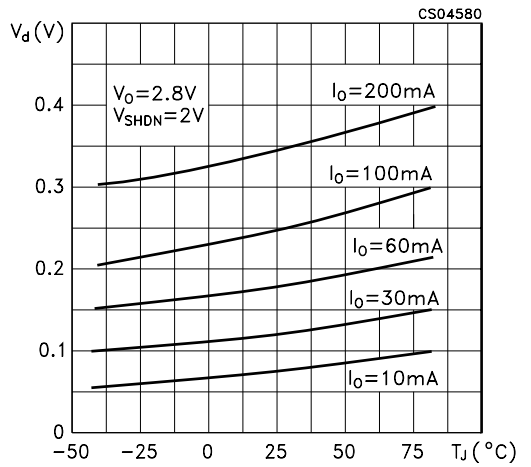


Figure 8: Short Circuit Current vs Dropout Voltage

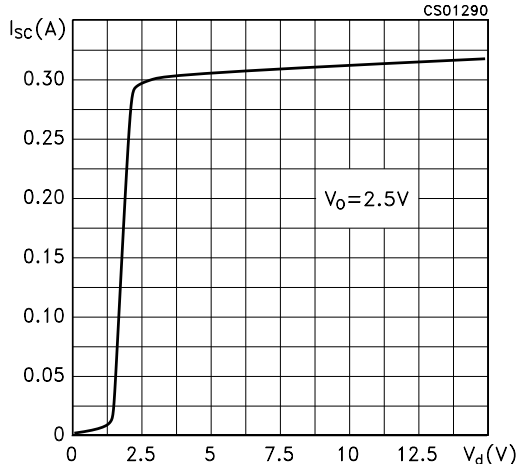


Figure 9: Output Voltage vs Input Voltage

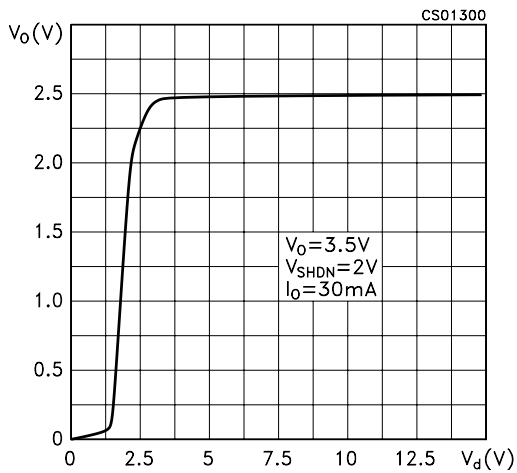


Figure 12: Supply Voltage Rejection vs Temperature

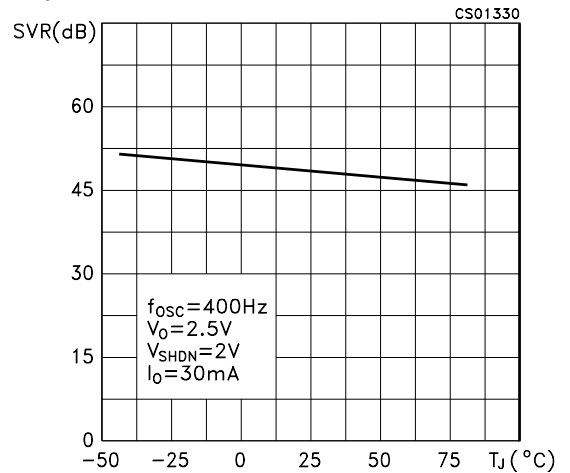


Figure 10: Shutdown Voltage vs Temperature

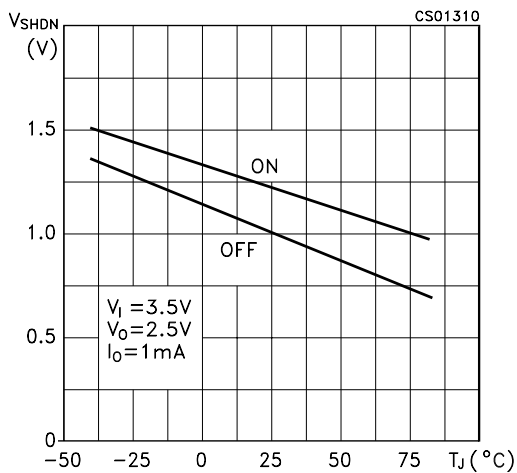


Figure 13: Supply Voltage Rejection vs Output Current

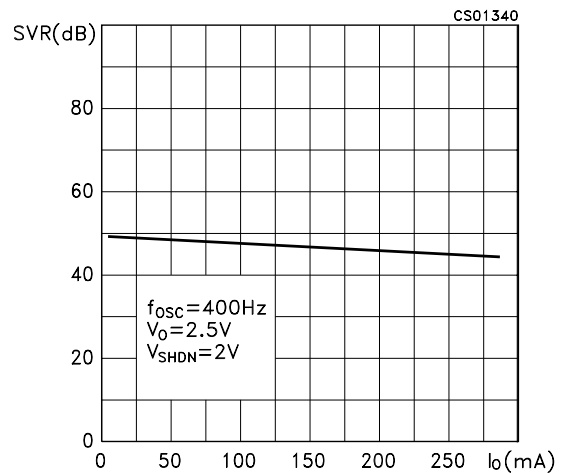


Figure 11: Shutdown Current vs Shutdown Voltage

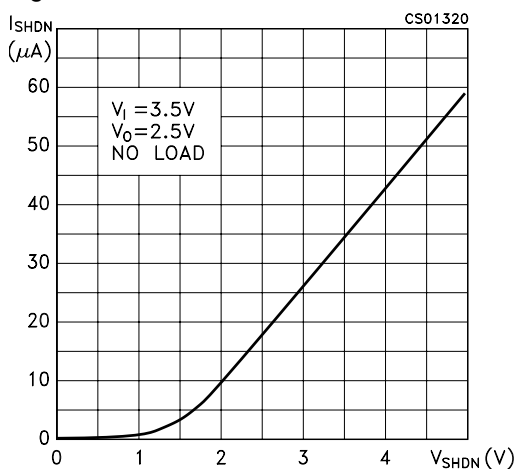


Figure 14: Supply Voltage Rejection vs Frequency

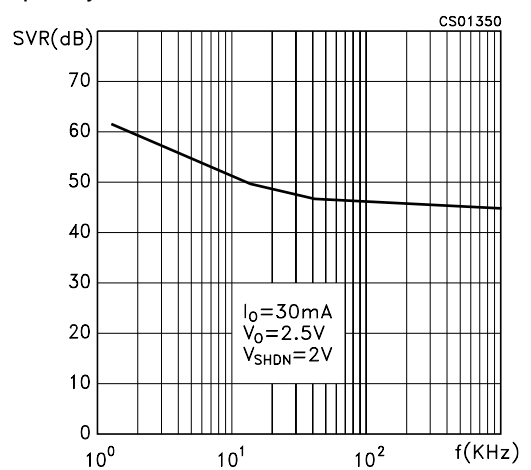


Figure 15: Supply Voltage Rejection vs Temperature

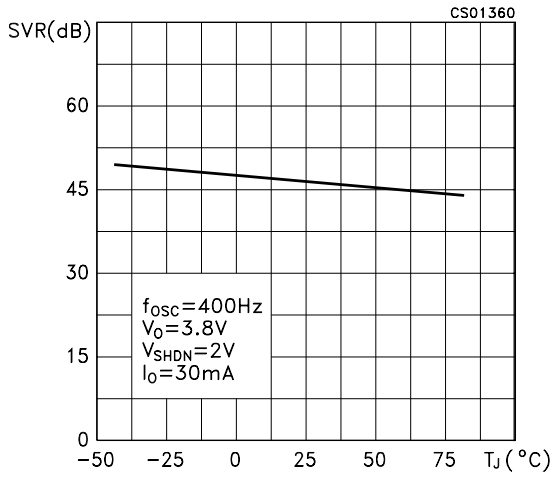


Figure 16: Quiescent Current vs Temperature

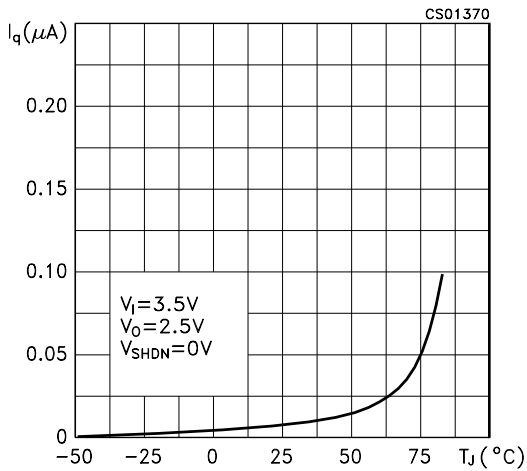


Figure 17: Quiescent Current vs Input Voltage

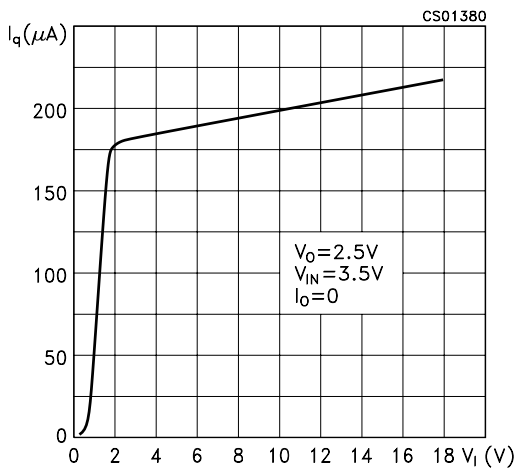


Figure 18: Quiescent Current vs Shutdown Voltage

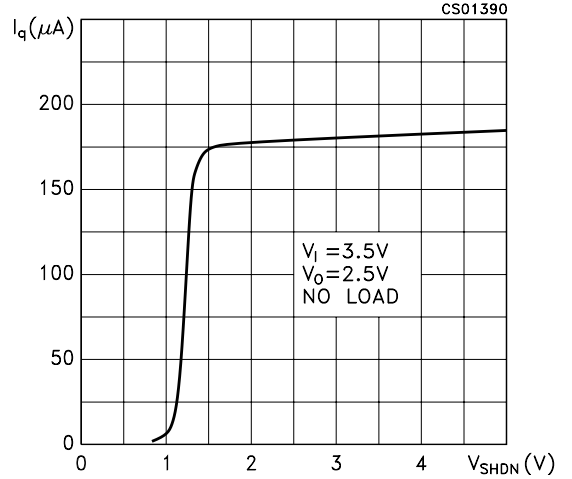


Figure 19: Quiescent Current vs Temperature

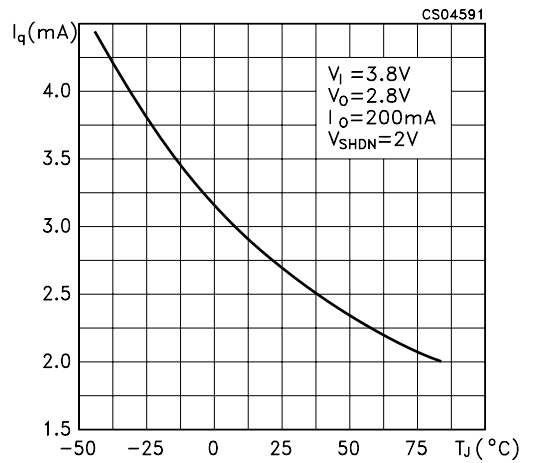


Figure 20: Reverse Current vs Reverse Voltage

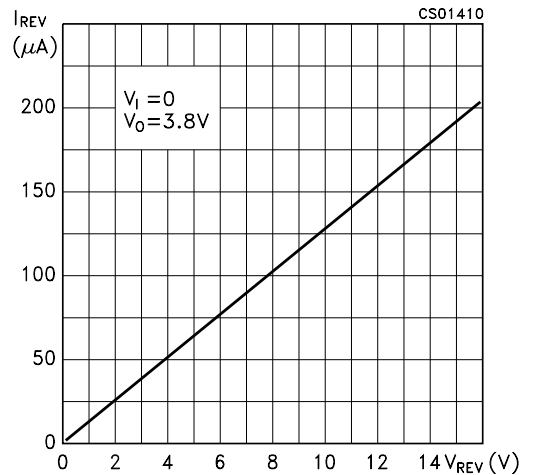


Figure 21: Stability

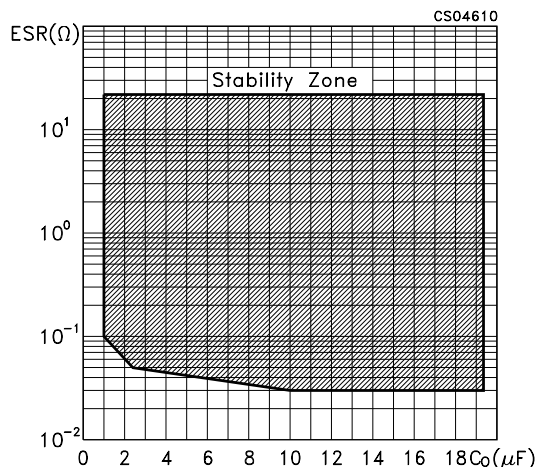


Figure 24: Start-up Transient

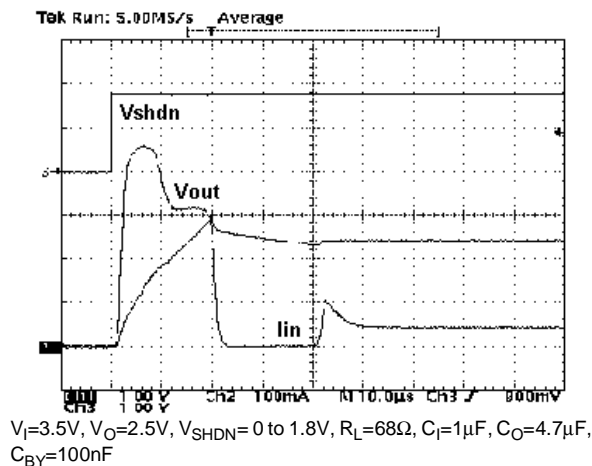


Figure 22: Spectrum Noise

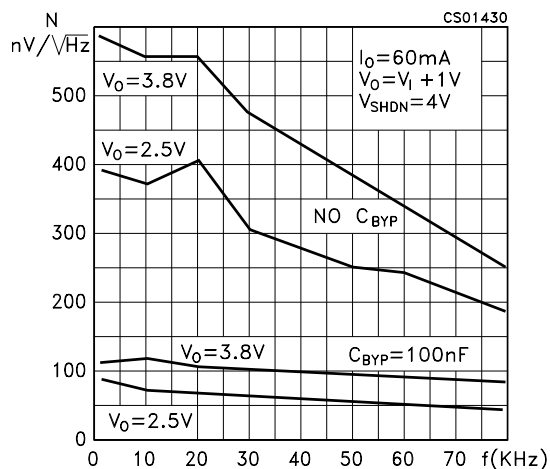


Figure 25: Line Transient

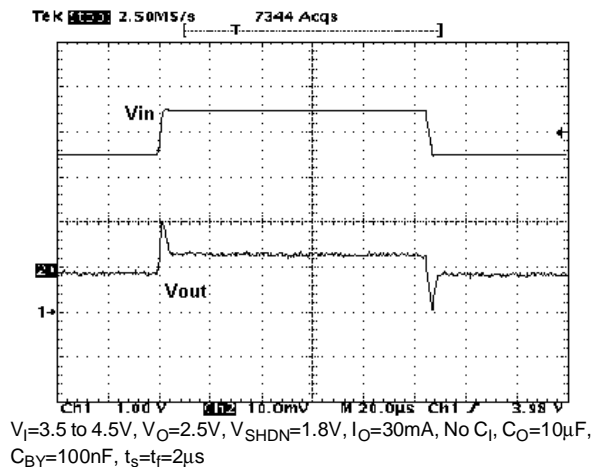


Figure 23: Start-up Transient

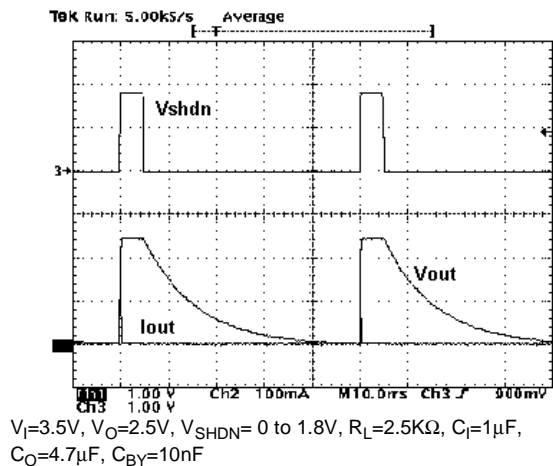


Figure 26: Line Transient

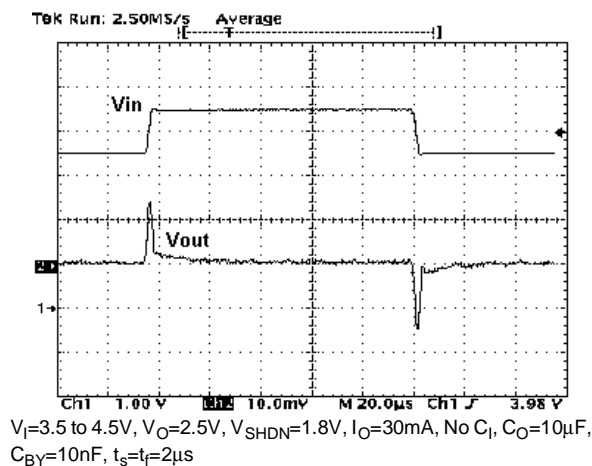


Figure 27: Line Transient

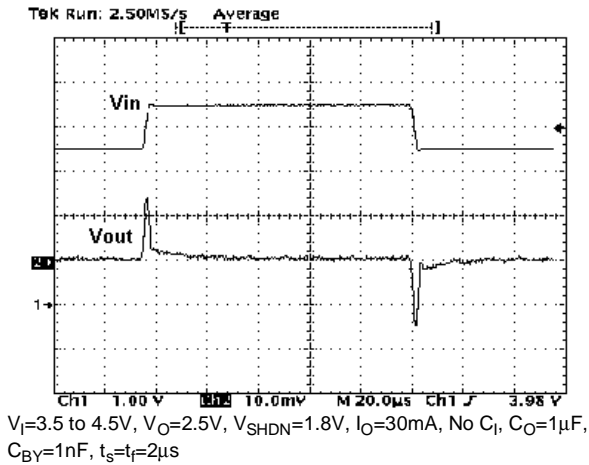


Figure 29: Load Transient

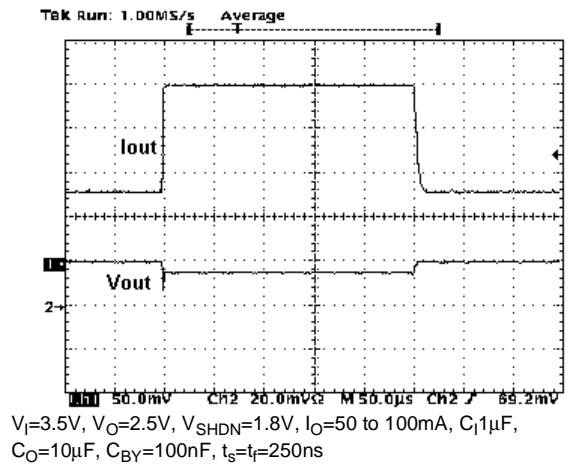


Figure 28: Load Transient

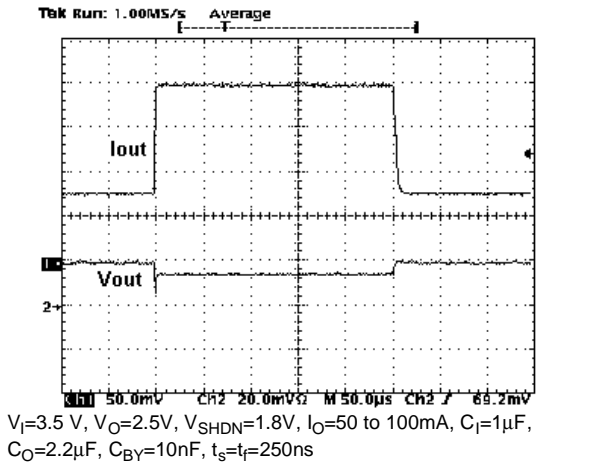
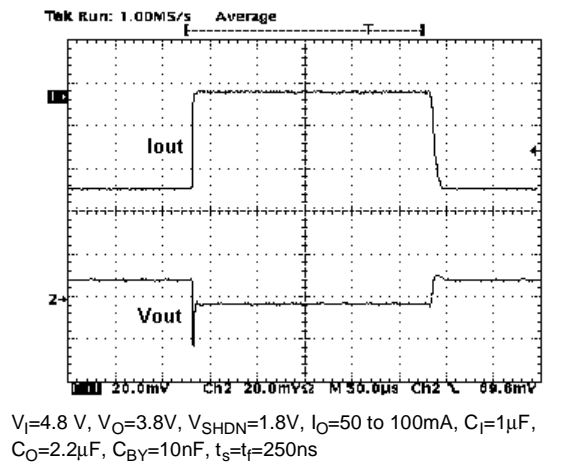
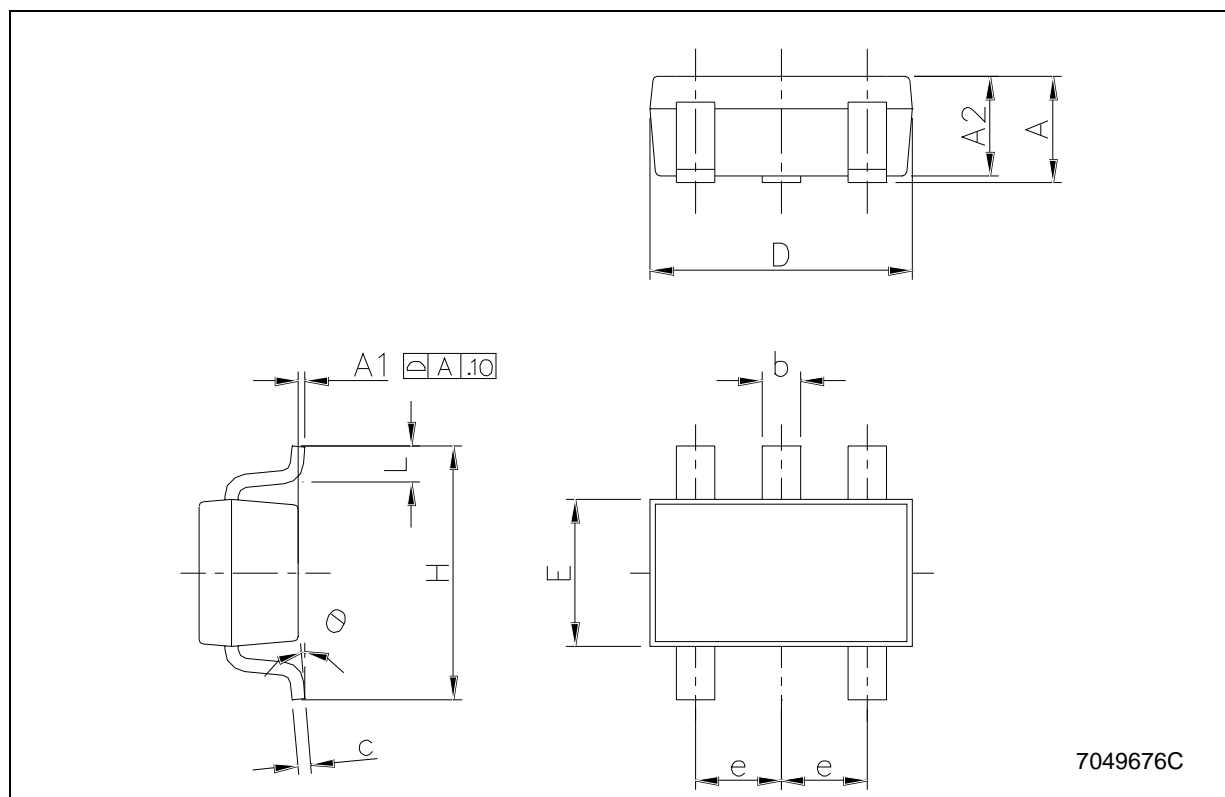


Figure 30: Load Transient



SOT23-5L MECHANICAL DATA

DIM.	mm.			mils		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A	0.90		1.45	35.4		57.1
A1	0.00		0.10	0.0		3.9
A2	0.90		1.30	35.4		51.2
b	0.35		0.50	13.7		19.7
C	0.09		0.20	3.5		7.8
D	2.80		3.00	110.2		118.1
E	1.50		1.75	59.0		68.8
e		0.95			37.4	
H	2.60		3.00	102.3		118.1
L	0.10		0.60	3.9		23.6



Tape & Reel SOT23-xL MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			180			7.086
C	12.8	13.0	13.2	0.504	0.512	0.519
D	20.2			0.795		
N	60			2.362		
T			14.4			0.567
Ao	3.13	3.23	3.33	0.123	0.127	0.131
Bo	3.07	3.17	3.27	0.120	0.124	0.128
Ko	1.27	1.37	1.47	0.050	0.054	0.058
Po	3.9	4.0	4.1	0.153	0.157	0.161
P	3.9	4.0	4.1	0.153	0.157	0.161

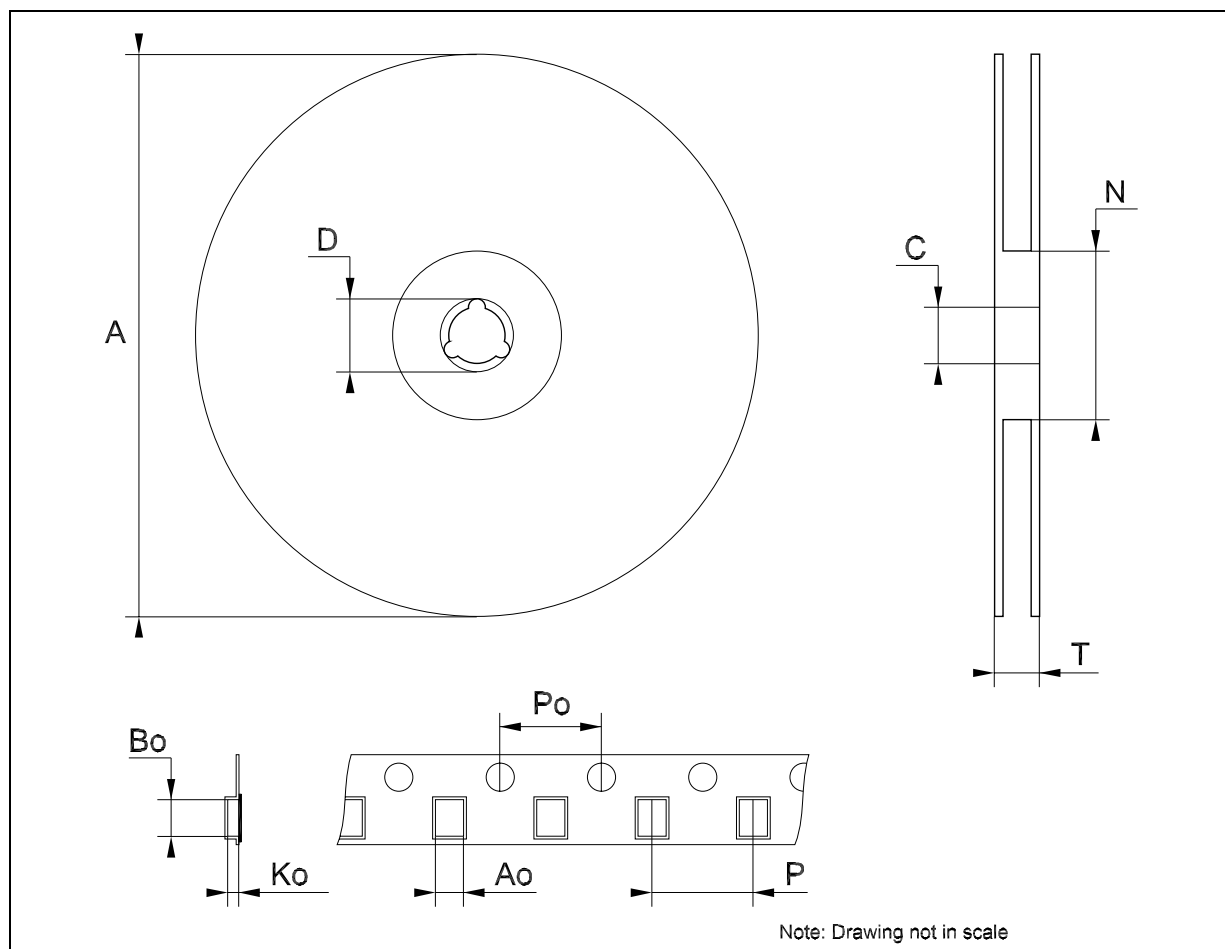


Table 5: Revision History

Date	Revision	Description of Changes
31-Aug-2004	2	Mistake on Fig. 19.
31-Jan-2005	3	Change Maturity Code.

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics

All other names are the property of their respective owners

© 2005 STMicroelectronics - All Rights Reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com